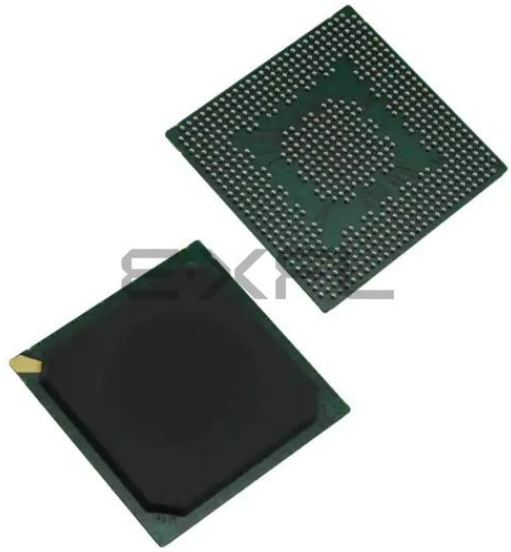

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	PowerPC e300c3
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	Security; SEC 3.3
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	Cryptography, Random Number Generator
Package / Case	620-BBGA Exposed Pad
Supplier Device Package	620-HBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8314ecvradda

- One floating point unit and two integer units
- Software-compatible with the Freescale processor families implementing the PowerPC Architecture
- Performance monitor

2.2 Serial Interfaces

The following interfaces are supported in the MPC8314E.

- Two enhanced TSECs (eTSECs)
- Two Ethernet interfaces using one RGMII/MII/RMII/RTBI or SGMII (no GMII)
- Dual UART, one I^2C, and one SPI interface

2.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, 802.11i, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are:

- Public key execution unit (PKEU)
  - RSA and Diffie-Hellman (to 4096 bits)
  - Programmable field size up to 2048 bits
  - Elliptic curve cryptography (1023 bits)
  - F2m and F(p) modes
  - Programmable field size up to 511 bits
- Data encryption standard execution unit (DEU)
  - DES, 3DES
  - Two key (K1, K2) or three key (K1, K2, K3)
  - ECB, CBC, CFB-64 and OFB-64 modes for both DES and 3DES
- Advanced encryption standard unit (AESU)
  - Implements the Rinjdael symmetric key cipher
  - Key lengths of 128, 192, and 256 bits
  - ECB, CBC, CCM, CTR, GCM, CMAC, OFB, CFB, XCBC-MAC and LRW modes
  - XOR acceleration
- Message digest execution unit (MDEU)
  - SHA with 160-bit, 256-bit, 384-bit and 512-bit message digest
  - SHA-384/512
  - MD5 with 128-bit message digest
  - HMAC with either algorithm
- Random number generator (RNG)

This table shows the estimated typical I/O power dissipation for this family of devices.

Table 5. MPC8314E Power Dissipation

Interface	Frequency	GV_{DD} (1.8 V)	GV_{DD} (2.5 V)	NV_{DD} (3.3 V)	LVDD1_OFF/ LVDD2_ON (3.3V)	LVDD2 _ON (3.3V)	VDD33PLL, VDD33ANA (3.3V)	SATA_VDD, VDD1IO, VDD1ANA (1.0V)	XCOREVDD, XPADVDD, SDAVDD (1.0V)	Unit
DDR 1 Rs = 22Ω Rt = 50Ω	266MHz, 32 bits	—	0.323	—	—	—	—	—	—	W
	200MHz, 32 bits	—	0.291	—	—	—	—	—	—	W
DDR 2 Rs = 22Ω Rt = 75Ω	266MHz, 32 bits	0.246	—	—	—	—	—	—	—	W
	200MHz, 32bits	0.225	—	—	—	—	—	—	—	W
PCI I/O load = 50pF	33 MHz	—	—	0.120	—	—	—	—	—	W
	66 MHz	—	—	0.249	—	—	—	—	—	W
Local bus I/O load = 20pF	66 MHz	—	—	—	—	0.056	—	—	—	W
	50 MHz	—	—	—	—	0.040	—	—	—	W
eTSEC I/O load = 20pF Multiple by number of interface used	MII, 25MHz	—	—	—	0.008	—	—	—	—	W
	RGMII, 125MHz (3.3V)	—	—	—	0.078	—	—	—	—	W
	RGMII, 125MHz (2.5V)	—	—	—	0.044	—	—	—	—	W
USBDR Controller (ULPI mode) load =20pF	60 MHz	—	—	—	0.078	—	—	—	—	W
USBDR+ Internal PHY (UTMI mode)	480 MHz	—	—	—	0.274	—	—	—	—	W
PCI Express two x1lane	2.5 GHz	—	—	—	—	—	—	—	0.190	W
Other I/O	—	—	—	0.015	—	—	—	—	—	W

5 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8314E.

5.1 DC Electrical Characteristics

This table provides the clock input (SYS_CLK_IN/PCI_SYNC_IN) DC timing specifications for the MPC8314E.

Table 6. SYS_CLK_IN DC Electrical Characteristics

Parameter	Condition	Symbol	Min	Max	Unit
Input high voltage	—	V_{IH}	2.4	NVDD + 0.3	V
Input low voltage	—	V_{IL}	-0.3	0.4	V
SYS_CLK_IN input current	0 V ≤V_{IN} ≤ NVDD	I_{IN}	—	±10	μA
SYS_XTAL_IN input current	0 V ≤V_{IN} ≤ NVDD	I_{IN}	—	±40	μA
PCI_SYNC_IN input current	0 V ≤V_{IN} ≤ NVDD	I_{IN}	—	±10	μA
RTC_CLK input current	0 V ≤V_{IN} ≤ NVDD	I_{IN}	—	±10	μA
USB_CLK_IN input current	0 V ≤ V_{IN} ≤ NVDD	I_{IN}	—	±10	μA
USB_XTAL_IN input current	0 V ≤V_{IN} ≤ NVDD	I_{IN}	—	±40	μA

5.2 AC Electrical Characteristics

The primary clock source for the MPC8314E can be one of two inputs, SYS_CLK_IN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode. This table provides the clock input (SYS_CLK_IN/PCI_CLK) AC timing specifications for the MPC8314E.

Table 7. SYS_CLK_IN AC Timing Specifications

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Note
SYS_CLK_IN/PCI_CLK frequency	$f_{SYS\_CLK\_IN}$	24	—	66.67	MHz	1, 6, 7
SYS_CLK_IN/PCI_CLK cycle time	$t_{SYS\_CLK\_IN}$	15	—	41.6	ns	6
SYS_CLK_IN rise and fall time	t_{KH}, t_{KL}	0.6	—	4	ns	2, 6
PCI_CLK rise and fall time	t_{PCH}, t_{PCL}	0.6	0.8	1.2	ns	2
SYS_CLK_IN/PCI_CLK duty cycle	$t_{KHK}/t_{SYS\_CLK\_IN}$	40	—	60	%	3, 6
SYS_CLK_IN/PCI_CLK jitter	—	—	—	±150	ps	4, 5, 6

Note:

1. **Caution:** The system, core, and security block must not exceed their respective maximum or minimum operating frequencies.
2. Rise and fall times for SYS_CLK_IN/PCI_CLK are specified at 20% to 80% of signal swing.
3. Timing is guaranteed by design and characterization.
4. This represents the total input jitter—short term and long term—and is guaranteed by design.
5. The SYS_CLK_IN/PCI_CLK driver's closed loop jitter bandwidth should be <500 kHz at –20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track SYS_CLK_IN drivers with the specified jitter.
6. The parameter names PCI_CLK and PCI_SYNC_IN are used interchangeably in this document.
7. Spread spectrum is allowed up to 1% down-spread at 33kHz.(max. rate).

Table 9. RESET Initialization Timing Specifications (continued)

Note:
1. $t_{PCI\_SYNC\_IN}$ is the clock period of the input clock applied to PCI_SYNC_IN. When the device is In PCI host mode the primary clock is applied to the SYS_CLK_IN input, and PCI_SYNC_IN period depends on the value of CFG_SYS_CLKIN_DIV.
2. $t_{SYS\_CLK\_IN}$ is the clock period of the input clock applied to SYS_CLK_IN. It is only valid when the device is in PCI host mode.
3. POR configuration signals consists of CFG_RESET_SOURCE[0:3] and CFG_SYS_CLKIN_DIV.
4. The parameter names CFG_SYS_CLKIN_DIV and CFG_CLKIN_DIV are used interchangeably in this document.

This table provides the PLL lock times.

Table 10. PLL Lock Times

Parameter/Condition	Min	Max	Unit	Note
System PLL lock times	—	100	μs	—
e300 core PLL lock times	—	100	μs	—
SerDes (SGMII/PCI Exp Phy) PLL lock times	—	100	μs	—
USB phy PLL lock times	—	100	μs	—

7 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface of the MPC8314E. Note that DDR SDRAM is GVDD(typ) = 2.5 V and DDR2 SDRAM is GVDD(typ) = 1.8 V.

7.1 DDR and DDR2 SDRAM DC Electrical Characteristics

This table provides the recommended operating conditions for the DDR2 SDRAM component(s) of the MPC8314E when GVDD(typ) = 1.8 V.

Table 11. DDR2 SDRAM DC Electrical Characteristics for GVDD(typ) = 1.8 V

Parameter/Condition	Symbol	Min	Max	Unit	Note
I/O supply voltage	GVDD	1.7	1.9	V	1
I/O reference voltage	MVREF	0.49 × GVDD	0.51 × GVDD	V	2
I/O termination voltage	V_{TT}	MVREF – 0.04	MVREF + 0.04	V	3
Input high voltage	V_{IH}	MVREF+ 0.125	GVDD + 0.3	V	—
Input low voltage	V_{IL}	–0.3	MVREF – 0.125	V	—
Output leakage current	I_{OZ}	–9.9	9.9	μA	4
Output high current (V_{OUT} = 1.420 V, GVDD= 1.7V)	I_{OH}	–13.4	—	mA	—
Output low current (V_{OUT} = 0.280 V)	I_{OL}	13.4	—	mA	

Note:
1. GVDD is expected to be within 50 mV of the DRAM GVDD at all times.
2. MVREF is expected to be equal to 0.5 × GVDD, and to track GVDD DC variations as measured at the receiver. Peak-to-peak noise on MVREF may not exceed ±2% of the DC value.
3. V_{TT} is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to MVREF. This rail should track variations in the DC level of MVREF.
4. Output leakage is measured with all outputs disabled, 0 V ≤ V_{OUT} ≤ GVDD.

9.1 eTSEC (10/100/1000 Mbps)—MII/RMII/RGMII/RTBI Electrical Characteristics

The electrical characteristics specified here apply to all the media-independent interface (MII), reduced gigabit MII (RGMII), and reduced ten-bit interface (RTBI) signals except management data input/output (MDIO) and management data clock (MDC). The MII and RMII is defined for 3.3 V, while the RGMII, and RTBI can operate at 2.5 V. The RGMII and RTBI follow the Hewlett-Packard reduced pin-count interface for Gigabit Ethernet Physical Layer Device Specification Version 1.2a (9/22/2000). The electrical characteristics for MDIO and MDC are specified in Section 9.3, "Ethernet Management Interface Electrical Characteristics."

9.1.1 MII, RMII, RGMII, and RTBI DC Electrical Characteristics

All MII, RMII drivers and receivers comply with the DC parametric attributes specified in Table 23 for 3.3-V operation and RGMII, RTBI drivers and receivers comply with the DC parametric attributes specified in Table 24. The RGMII and RTBI signals are based on a 2.5 V CMOS interface voltage as defined by JEDEC EIA/JESD8–5.

NOTE

eTSEC should be interfaced with peripheral operating at same voltage level.

Table 23. MII/RMII (When Operating at 3.3 V) DC Electrical Characteristics

Parameter	Symbol	Conditions		Min	Max	Unit
Supply voltage 3.3 V	LVDD	—	—	3.0	3.6	V
Output high voltage	V_{OH}	I_{OH} = –4.0 mA	LVDD = Min	2.40	LVDD + 0.3	V
Output low voltage	V_{OL}	I_{OL} = 4.0 mA	LVDD = Min	V_{SS}	0.50	V
Input high voltage	V_{IH}	—	—	2.1	LVDD + 0.3	V
Input low voltage	V_{IL}	—	—	–0.3	0.90	V
Input high current	I_{IH}	V_{IN} [1] = LVDD		—	40	μA
Input low current	I_{IL}	V_{IN} [1] = VSS		–600	—	μA

Note:
1. The symbol V_{IN}, in this case, represents the LV_{IN} symbol referenced in Table 1 and Table 2.

Table 24. RGMII/RTBI (When Operating at 2.5 V) DC Electrical Characteristics

Parameters	Symbol	Conditions		Min	Max	Unit
Supply voltage 2.5 V	LVDD	—	—	2.37	2.63	V
Output high voltage	V_{OH}	I_{OH} = –1.0 mA	LVDD = Min	2.00	LVDD + 0.3	V
Output low voltage	V_{OL}	I_{OL} = 1.0 mA	LVDD = Min	V_{SS} – 0.3	0.40	V
Input high voltage	V_{IH}	—	LVDD = Min	1.7	LVDD + 0.3	V
Input low voltage	V_{IL}	—	LVDD =Min	–0.3	0.70	V
Input high current	I_{IH}	V_{IN} [1] = LVDD		—	15	μA
Input low current	I_{IL}	V_{IN} [1] = VSS		–15	—	μA

Table 28. RMII Receive AC Timing Specifications (continued)

At recommended operating conditions with LVDD of 3.3 V ± 300 mv

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
RXD[1:0], CRS_DV, RX_ER setup time to REF_CLK	$t_{RMRDVKH}$	4.0	—	—	ns
RXD[1:0], CRS_DV, RX_ER hold time to REF_CLK	$t_{RMRDXKH}$	2.0	—	—	ns
REF_CLK clock rise V_{IL}(min) to V_{IH}(max)	t_{RMXR}	1.0	—	4.0	ns
REF_CLK clock fall time V_{IH}(max) to V_{IL}(min)	t_{RMXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first three letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{RMRDVKH}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{RMX} clock reference (K) going to the high (H) state or setup time. Also, $t_{RMRDXKL}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) went invalid (X) relative to the t_{RMX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{RMX} represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

This figure provides the AC test load.

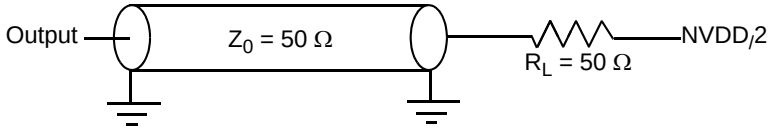


Figure 13. AC Test Load

This figure shows the RMII receive AC timing diagram.

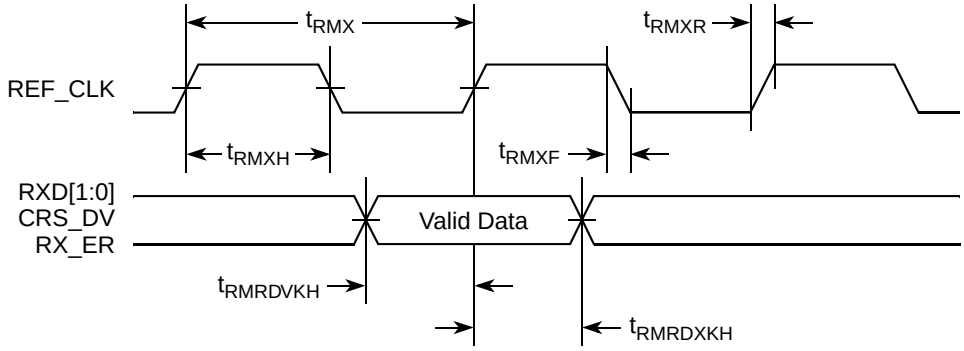


Figure 14. RMII Receive AC Timing Diagram

9.2.3 RGMII and RTBI AC Timing Specifications

This table presents the RGMII and RTBI AC timing specifications.

Table 29. RGMII and RTBI AC Timing Specifications

At recommended operating conditions (see Table 2)

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
Data to clock output skew (at transmitter)	t_{SKRGT}	–0.6	—	0.6	ns
Data to clock input skew (at receiver) [2]	t_{SKRGT}	1.0	—	2.6	ns

This figure shows the RGMII and RTBI AC timing and multiplexing diagrams.

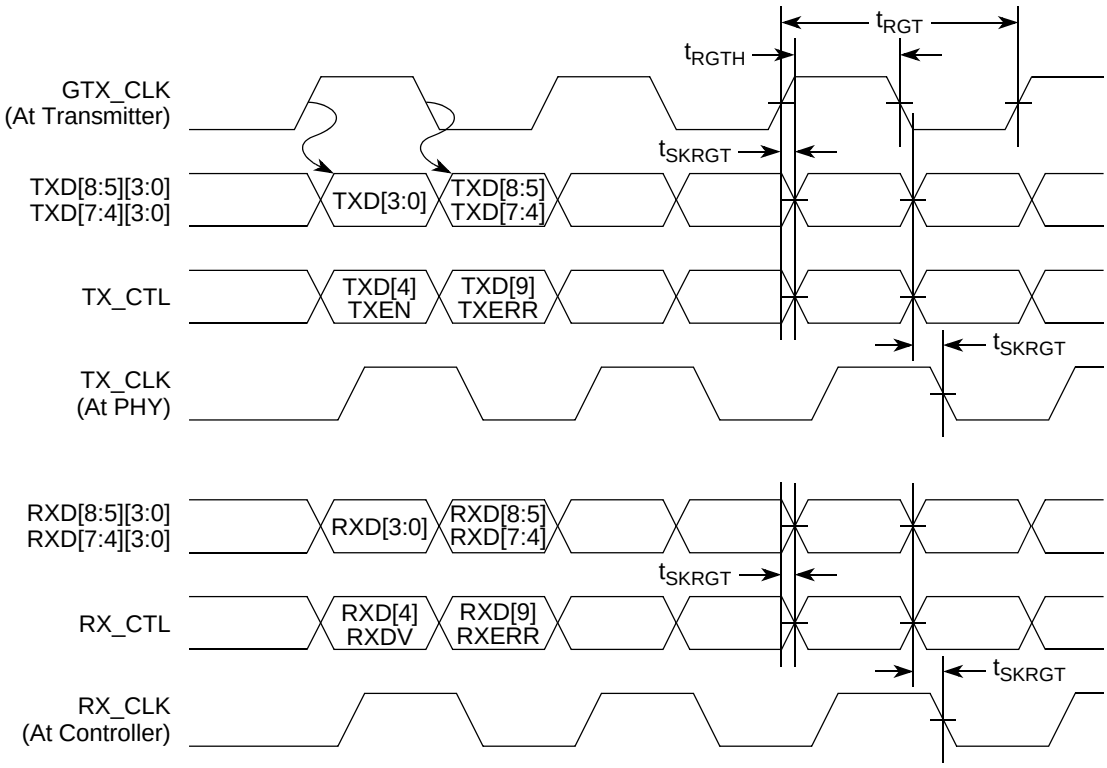


Figure 15. RGMII and RTBI AC Timing and Multiplexing Diagrams

9.3 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals management data input/output (MDIO) and management data clock (MDC). The electrical characteristics for MII, RMII, RGMII, and RTBI are specified in Section 9.1, "eTSEC (10/100/1000 Mbps)—MII/RMII/RGMII/RTBI Electrical Characteristics."

9.3.1 MII Management DC Electrical Characteristics

The MDC and MDIO are defined to operate at a supply voltage of 3.3 V. The DC electrical characteristics for MDIO and MDC are provided in this table.

Table 30. MII Management DC Electrical Characteristics Powered at 3.3 V

Parameter	Symbol	Conditions		Min	Max	Unit
Supply voltage (3.3 V)	NVDD	—	—	3.0	3.6	V
Output high voltage	V_{OH}	I_{OH} = –1.0 mA	NVDD = Min	2.10	NVDD + 0.3	V
Output low voltage	V_{OL}	I_{OL} = 1.0 mA	NVDD = Min	V_{SS}	0.50	V
Input high voltage	V_{IH}	—	—	2.00	—	V
Input low voltage	V_{IL}	—	—	—	0.80	V
Input high current	I_{IH}	NVDD = Max	V_{IN} [1] = 2.1 V	—	40	μA

Table 30. MII Management DC Electrical Characteristics Powered at 3.3 V (continued)

Parameter	Symbol	Conditions		Min	Max	Unit
Input low current	I_{IL}	NVDD = Max	V_{IN} = 0.5 V	–600	—	μA

Note:
1. The symbol V_{IN}, in this case, represents the NV_{IN} symbol referenced in Table 1 and Table 2.

9.3.2 MII Management AC Electrical Specifications

This table provides the MII management AC timing specifications.

Table 31. MII Management AC Timing Specifications

At recommended operating conditions with NVDD is 3.3 V ± 300 mv

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit	Note
MDC frequency	f_{MDC}	—	2.5	—	MHz	2
MDC period	t_{MDC}	—	400	—	ns	—
MDC clock pulse width high	t_{MDCH}	32	—	—	ns	—
MDC to MDIO delay	t_{MDKHDX}	10	—	170	ns	3
MDIO to MDC setup time	t_{MDDVKH}	5	—	—	ns	—
MDIO to MDC hold time	t_{MDDXKH}	0	—	—	ns	—
MDC rise time	t_{MDCR}	—	—	10	ns	—
MDC fall time	t_{MDHF}	—	—	10	ns	—

Note:
1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{MDKHDX} symbolizes management data timing (MD) for the time t_{MDC} from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t_{MDDVKH} symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MDC} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. This parameter is dependent on the csb_clk speed (that is, for a csb_clk of 133 MHz, the maximum frequency is 4.16 MHz and the minimum frequency is 0.593 MHz).
3. This parameter is dependent on the csb_clk speed (that is, for a csb_clk of 133 MHz, the delay is 60 ns).

Table 40. USB General Timing Parameters (continued)

Parameter	Symbol [1]	Min	Max	Unit	Note
USB clock to output valid—all outputs	t_{USKHOV}	—	9	ns	1
Output hold from USB clock—all outputs	t_{USKHOX}	1	—	ns	1

Note:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(First two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(First two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{USIXKH} symbolizes USB timing (US) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also, t_{USKHOX} symbolizes USB timing (US) for the us clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to USB clock.
3. All signals are measured from NVDD/2 of the rising edge of USB clock to 0.4 × NVDD of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5. For purposes of active/float timing measurements, the Hi-Z or off-state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

Figure 21 and Figure 22 provide the AC test load and signals for the USB, respectively.

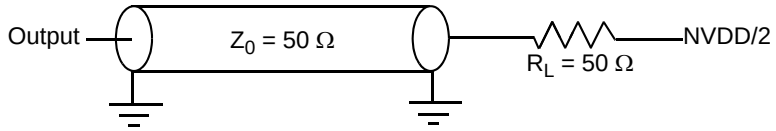


Figure 21. USB AC Test Load

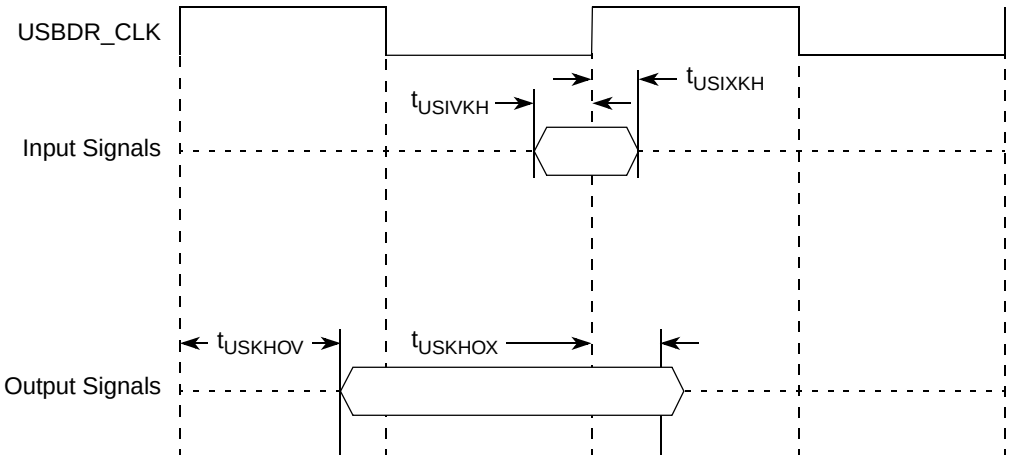


Figure 22. USB Signals

10.2 On-Chip USB PHY

This section provides the AC and DC electrical specifications for the USB PHY interface of the MPC8314E.

For details refer to Tables 7-7 through 7-10, and Table 7-14 in the *USB 2.0 Specifications document*, and the pull-up/down resistors ECN updates, all available at www.usb.org.

This table provides the USB clock input (USB_CLK_IN) DC timing specifications.

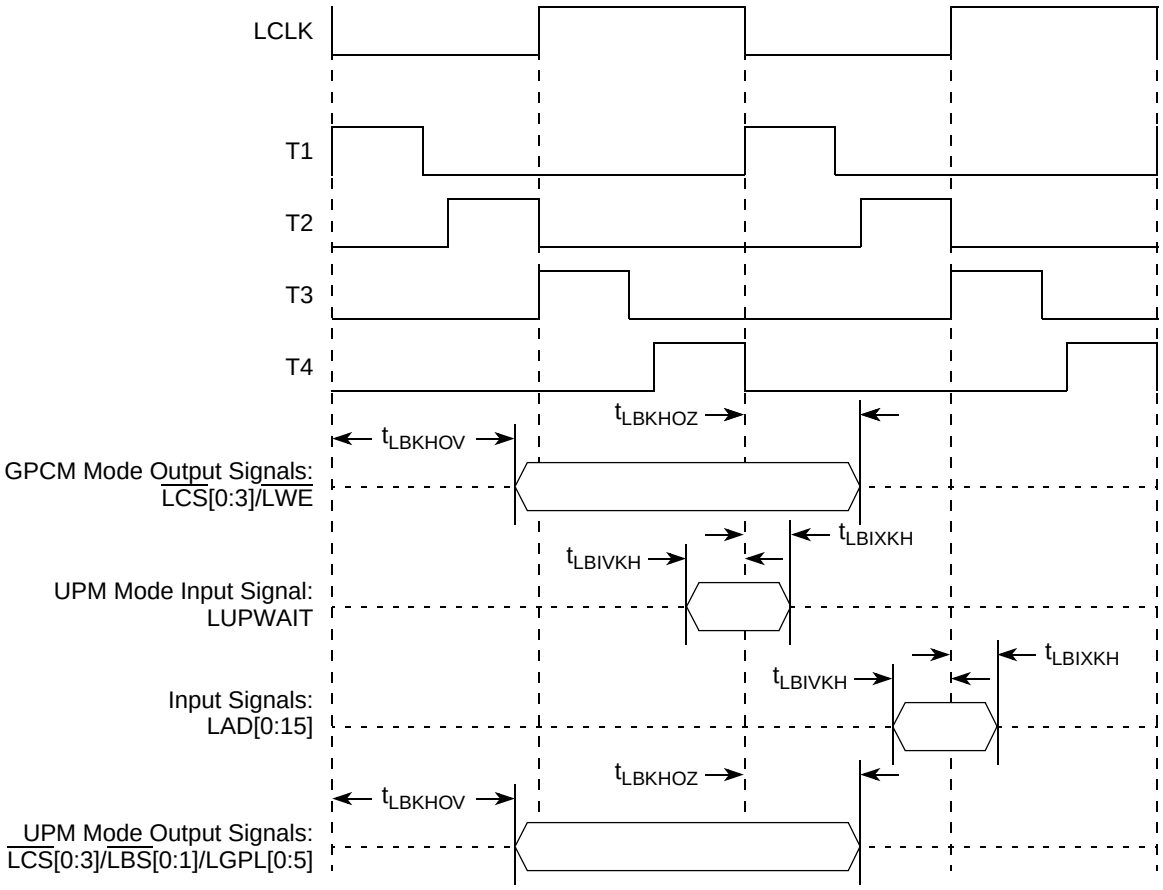


Figure 26. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4

12 JTAG

This section describes the DC and AC electrical specifications for the IEEE Std 1149.1™ (JTAG) interface.

12.1 JTAG DC Electrical Characteristics

This table provides the DC electrical characteristics for the IEEE 1149.1 (JTAG) interface.

Table 45. JTAG Interface DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Input high voltage	V_{IH}	—	2.1	NVDD + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	—	—	±5	μA
Output high voltage	V_{OH}	I_{OH} = –8.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 8.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V

This figure shows the AC timing diagram for the I^2C bus.

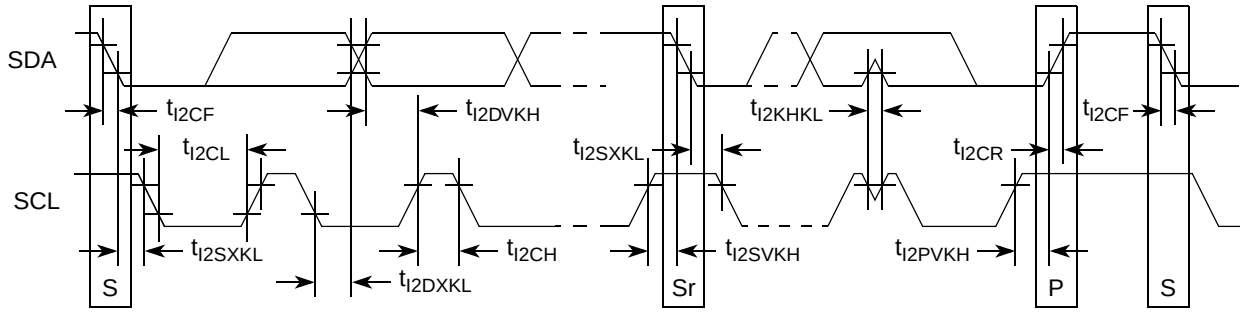


Figure 33. I^2C Bus AC Timing Diagram

14 PCI

This section describes the DC and AC electrical specifications for the PCI bus of the MPC8314E.

14.1 PCI DC Electrical Characteristics

This table provides the DC electrical characteristics for the PCI interface.

Table 49. PCI DC Electrical Characteristics [1]

Parameter	Symbol	Test Condition	Min	Max	Unit
High-level input voltage	V_{IH}	$V_{OUT} \geq V_{OH}$ (min) or	0.5 x NVDD	NVDD + 0.3	V
Low-level input voltage	V_{IL}	$V_{OUT} \leq V_{OL}$ (max)	–0.5	0.3 × NVDD	V
High-level output voltage	V_{OH}	NVDD = min, I_{OH} = –500 µA	0.9 x NVDD	—	V
Low-level output voltage	V_{OL}	NVDD = min, I_{OL} = 1500 µA	—	0.1 x NVDD	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ NVDD	—	± 10	µA

Note:
1. The symbol V_{IN}, in this case, represents the NV_{IN} symbol referenced in Table 1 and Table 2.

14.2 PCI AC Electrical Specifications

This section describes the general AC timing parameters of the PCI bus. Note that the PCI_CLK or PCI_SYNC_IN signal is used as the PCI input clock depending on whether the MPC8314E is configured as a host or agent device. This table shows the PCI AC timing specifications at 66 MHz.

Table 50. PCI AC Timing Specifications at 66 MHz

Parameter	Symbol [1]	Min	Max	Unit	Note
Clock to output valid	t_{PCKHOV}	—	6.0	ns	2
Output hold from clock	t_{PCKHOX}	1	—	ns	2
Clock to output high impedance	t_{PCKHOZ}	—	14	ns	2, 3
Input setup to clock	t_{PCIVKH}	3.3	—	ns	2, 4

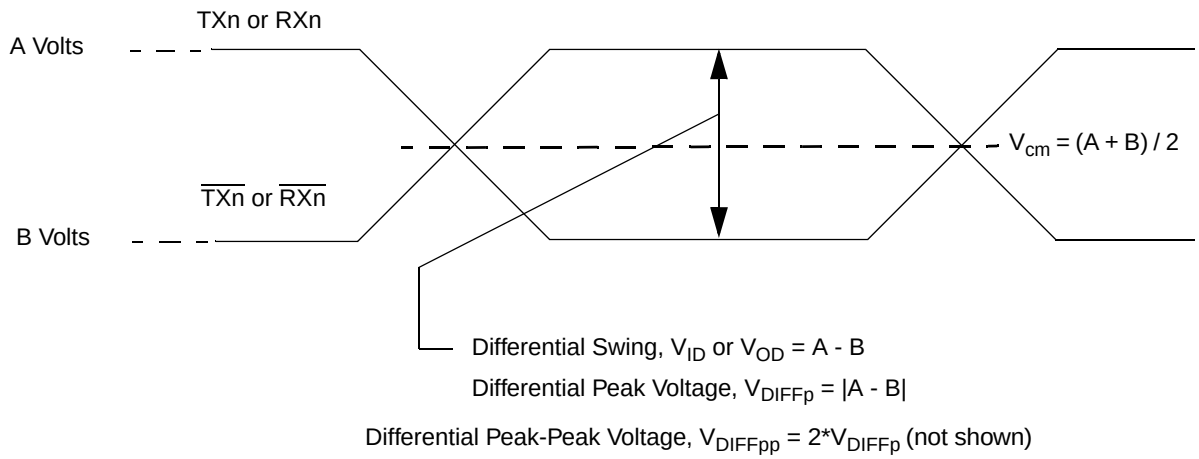


Figure 37. Differential Voltage Definitions for Transmitter or Receiver

To illustrate these definitions using real values, consider the case of a CML (Current Mode Logic) transmitter that has a common mode voltage of 2.25 V and each of its outputs, TD and $\overline{TD}$, has a swing that goes between 2.5V and 2.0V. Using these values, the peak-to-peak voltage swing of each signal (TD or $\overline{TD}$) is 500 mV p-p, which is referred as the single-ended swing for each signal. In this example, since the differential signaling environment is fully symmetrical, the transmitter output's differential swing (V_{OD}) has the same amplitude as each signal's single-ended swing. The differential output signal ranges between 500 mV and –500 mV, in other words, V_{OD} is 500 mV in one phase and –500 mV in the other phase. The peak differential voltage (V_{DIFFp}) is 500 mV. The peak-to-peak differential voltage ($V_{DIFFp-p}$) is 1000 mV p-p.

15.2 SerDes Reference Clocks

The SerDes reference clock inputs are applied to an internal PLL whose output creates the clock used by the corresponding SerDes lanes. The SerDes reference clocks input is SD_REF_CLK and $\overline{SD\_REF\_CLK}$ for PCI Express and SGMII interface.

The following sections describe the SerDes reference clock requirements and some application information.

15.2.1 SerDes Reference Clock Receiver Characteristics

Figure 38 shows a receiver reference diagram of the SerDes reference clocks.

- The supply voltage requirements for XCOREVDD are specified in Table 1 and Table 2.
- SerDes Reference Clock Receiver Reference Circuit Structure
  - The SD_REF_CLK and $\overline{SD\_REF\_CLK}$ are internally AC-coupled differential inputs as shown in Figure 38. Each differential clock input (SD_REF_CLK or $\overline{SD\_REF\_CLK}$) has a 50-Ω termination to XCOREVSS followed by on-chip AC-coupling.
  - The external reference clock driver must be able to drive this termination.
  - The SerDes reference clock input can be either differential or single-ended. Refer to the Differential Mode and Single-ended Mode description below for further detailed requirements.

16 PCI Express

This section describes the DC and AC electrical specifications for the PCI Express bus of the MPC8315E.

16.1 DC Requirements for PCI Express SD_REF_CLK and SD_REF_CLK

For more information, see Section 15.2, "SerDes Reference Clocks."

16.2 AC Requirements for PCI Express SerDes Clocks

This table lists the PCI Express SerDes clock AC requirements.

Table 53. SD_REF_CLK and SD_REF_CLK AC Requirements

Symbol	Parameter Description	Min	Typ	Max	Unit	Note
t_{REF}	REFCLK cycle time	—	10	—	ns	—
t_{REFCJ}	REFCLK cycle-to-cycle jitter. Difference in the period of any two adjacent REFCLK cycles.	—	—	100	ps	—
t_{REFPJ}	Phase jitter. Deviation in edge location with respect to mean edge location.	–50	—	50	ps	—

16.3 Clocking Dependencies

The ports on the two ends of a link must transmit data at a rate that is within 600 parts per million (ppm) of each other at all times. This is specified to allow bit rate clock sources with a ±300 ppm tolerance.

16.4 Physical Layer Specifications

Following is a summary of the specifications for the physical layer of PCI Express on this device. For further details as well as the specifications of the transport and data link layer please use the *PCI Express Base Specification*, Rev. 1.0a.

16.4.1 Differential Transmitter (TX) Output

This table defines the specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins.

Table 54. Differential Transmitter (TX) Output Specifications

Parameter	Symbol	Comments	Min	Typical	Max	Unit	Note
Unit interval	UI	Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations.	399.88	400	400.12	ps	1
Differential peak-to-peak output voltage	$V_{TX-DIFFp-p}$	$V_{TX-DIFFp-p} = 2*\|V_{TX-D+} - V_{TX-D-}\|$	0.8	—	1.2	V	2

16.4.2 Transmitter Compliance Eye Diagrams

The TX eye diagram in Figure 49 is specified using the passive compliance/test measurement load (see Figure 51) in place of any real PCI Express interconnect + RX component. There are two eye diagrams that must be met for the transmitter. Both diagrams must be aligned in time using the jitter median to locate the center of the eye diagram. The different eye diagrams differ in voltage depending on whether it is a transition bit or a de-emphasized bit. The exact reduced voltage level of the de-emphasized bit is always relative to the transition bit.

The eye diagram must be valid for any 250 consecutive UIs.

A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. The eye diagram is created using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI.

NOTE

It is recommended that the recovered TX UI be calculated using all edges in the 3500 consecutive UI interval with a fit algorithm using a minimization merit function (that is, least squares and median deviation fits).

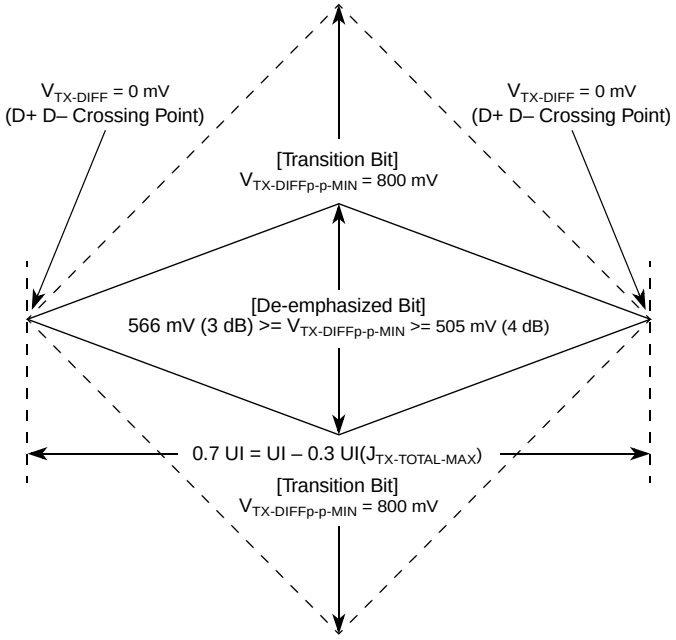


Figure 49. Minimum Transmitter Timing and Voltage Output Compliance Specifications

16.4.3 Differential Receiver (RX) Input Specifications

This table defines the specifications for the differential input at all receivers (RXs). The parameters are specified at the component pins.

Table 55. Differential Receiver (RX) Input Specifications

Parameter	Symbol	Comments	Min	Typical	Max	Unit	Note
Unit interval	UI	Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations.	399.88	400	400.12	ps	1
Differential peak-to-peak output voltage	$V_{RX-DIFFp-p}$	$V_{RX-DIFFp-p} = 2*\|V_{RX-D+} - V_{RX-D-}\|$	0.175	—	1.200	V	2
Minimum receiver eye width	T_{RX-EYE}	The maximum interconnect media and Transmitter jitter that can be tolerated by the Receiver can be derived as $T_{RX-MAX-JITTER} = 1 - U_{RX-EYE}$= 0.6 UI.	0.4	—	—	UI	2, 3
Maximum time between the jitter median and maximum deviation from the median.	$T_{RX-EYE-MEDIAN-to-MAX-JITTER}$	Jitter is defined as the measurement variation of the crossing points ($V_{RX-DIFFp-p}$ = 0 V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI.	—	—	0.3	UI	2, 3, 7
AC peak common mode input voltage	$V_{RX-CM-ACp}$	$V_{RX-CM-ACp} = \|V_{RXD+} + V_{RXD-}\|/2 - V_{RX-CM-DC}$ $V_{RX-CM-DC} = DC_{(avg)}$ of $\|V_{RX-D+} + V_{RX-D-}\|/2$	—	—	150	mV	2
Differential return loss	$RL_{RX-DIFF}$	Measured over 50 MHz to 1.25 GHz with the D+ and D- lines biased at +300 mV and -300 mV, respectively.	15	—	—	dB	4
Common mode return loss	RL_{RX-CM}	Measured over 50 MHz to 1.25 GHz with the D+ and D- lines biased at 0 V.	6	—	—	dB	4
DC differential input impedance	$Z_{RX-DIFF-DC}$	RX DC differential mode impedance.	80	100	120	Ω	5
DC Input Impedance	Z_{RX-DC}	Required RX D+ as well as D- DC Impedance (50 ± 20% tolerance).	40	50	60	Ω	2, 5

This figure shows the TDM transmit signal timing.

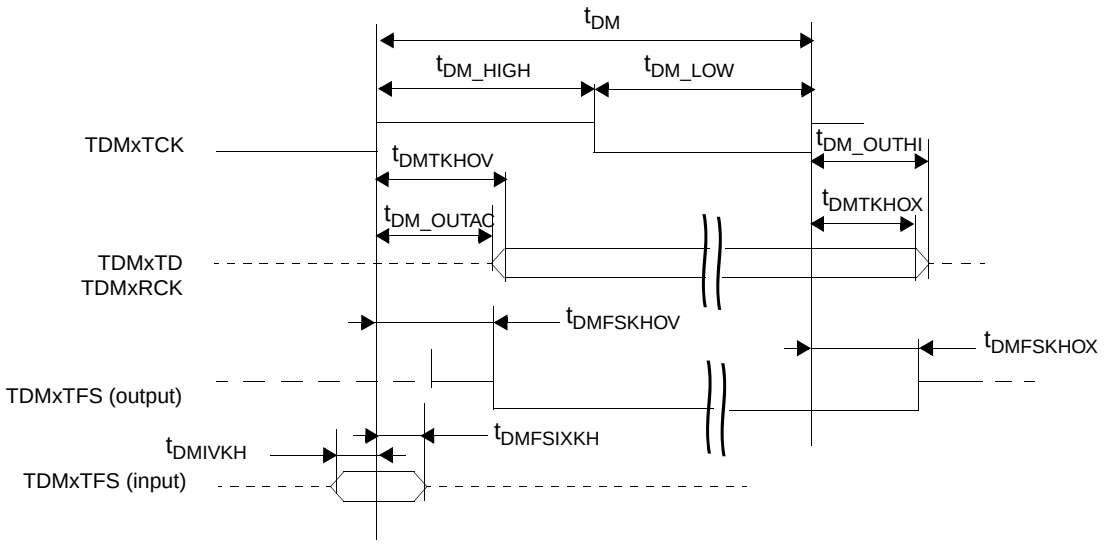


Figure 58. TDM Transmit Signals

22 Package and Pin Listings

This section details package parameters, pin assignments, and dimensions. The MPC8314E is available in a thermally enhanced plastic ball grid array (TEPBGA II), see Section 22.1, "Package Parameters for the MPC8314E TEPBGA II," and Section 22.2, "Mechanical Dimensions of the TEPBGA II," for information on the TEPBGA II.

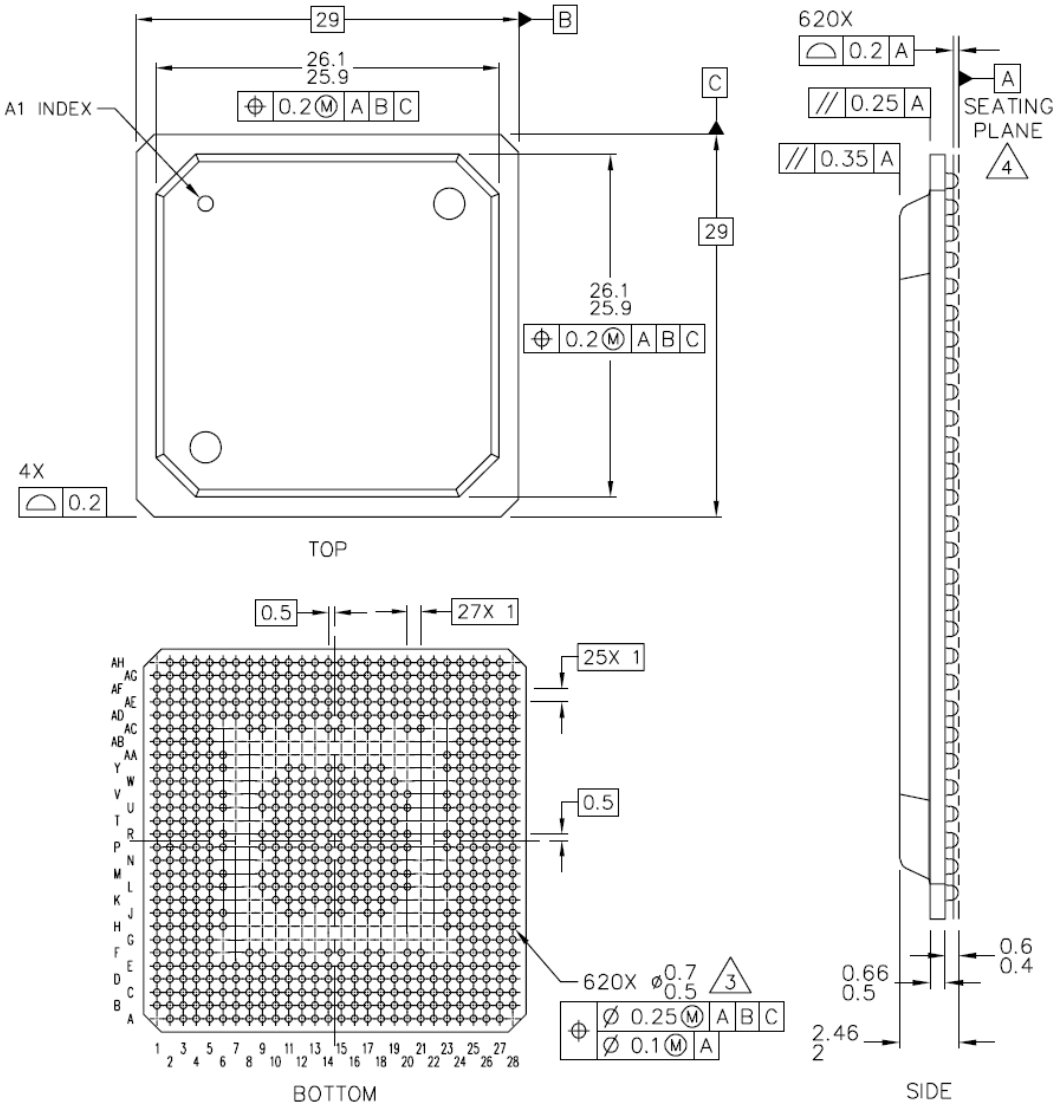
22.1 Package Parameters for the MPC8314E TEPBGA II

The package parameters are as provided in the following list. The package type is 29 mm × 29 mm, TEPBGA II.

Package outline	29 mm × 29 mm
Interconnects	620
Pitch	1 mm
Module height (typical)	2.23 mm
Solder balls	96.5 Sn/3.5 Ag (VR package)
Ball diameter (typical)	0.6 mm

22.2 Mechanical Dimensions of the TEPBGA II

This figure shows the mechanical dimensions and bottom surface nomenclature of the 620-pin TEPBGA II package.



Notes:
1. All dimensions are in millimeters.
2. Dimensions and tolerances per ASME Y14.5M-1994.
3. Maximum solder ball diameter measured parallel to datum A.
4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.

Figure 59. Mechanical Dimensions and Bottom Surface Nomenclature of the TEPBGA II

22.3 Pinout Listings

This table provides the pin-out listing for the TEPBGA II package.

Table 66. MPC8314E TEPBGA II Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Note
TSEC2_TXD[1]/CFG_RESET_SOURCE[2]	E8	I/O	LVDD2_ON	—
TSEC2_TXD[0]/CFG_RESET_SOURCE[3]	B7	I/O	LVDD2_ON	—
TSEC2_TX_EN	D12	O	LVDD2_ON	—
TSEC2_TX_ER	B11	O	LVDD2_ON	—
SGMII / PCI Express PHY				
TXA	P4	O	XPADVDD	—
$\overline{\text{TXA}}$	N4	O	XPADVDD	—
RXA	R1	I	XCOREVDD	—
$\overline{\text{RXA}}$	P1	I	XCOREVDD	—
TXB	U4	O	XPADVDD	—
$\overline{\text{TXB}}$	V4	O	XPADVDD	—
RXB	U1	I	XCOREVDD	—
$\overline{\text{RXB}}$	V1	I	XCOREVDD	—
SD_IMP_CAL_RX	N3	I	XCOREVDD	—
$\overline{\text{SD\_REF\_CLK}}$	R4	I	XCOREVDD	—
SD_REF_CLK	R5	I	XCOREVDD	—
SD_PLL_TPD	T2	O	—	—
SD_IMP_CAL_TX	V5	I	XPADVDD	—
SDAVDD	T3	I	—	—
SD_PLL_TPA_ANA	T4	O	—	—
SDAVSS	T5	I	—	—
USB Phy				
USB_DP	A11	I/O	USB_VDDA	—
USB_DM	A12	I/O	USB_VDDA	—
USB_VBUS	C12	I	—	—
USB_TPA	A14	O	—	—
USB_RBIAS	D14	I	—	8
USB_PLL_PWR3	A13	I	—	—
USB_PLL_GND0 & USB_PLL_GND1	D13	I	—	—
USB_PLL_PWR1	B13	I	—	—
USB_VSSA_BIAS	E14	I	—	—
USB_VDDA_BIAS	C14	I	—	—
USB_VSSA	E13	I	—	—
USB_VDDA	E12	I	—	—
GPIO				
GPIO_0/$\overline{\text{DMA\_DREQ1}}$/$\overline{\text{GTM1\_TOUT1}}$	C5	I/O	NVDD1_ON	—

Table 75. Heat Sinks and Junction-to-Case Thermal Resistance of MPC8314E TEPBGA II

Heat Sink Assuming Thermal Grease	Air Flow	29 × 29 mm TEBGA II
		Junction-to-Ambient Thermal Resistance
AAVID 30 x 30 x 9.4 mm Pin Fin	Natural Convection	14.4
AAVID 30 x 30 x 9.4 mm Pin Fin	0.5 m/s	11.4
AAVID 30 x 30 x 9.4 mm Pin Fin	1 m/s	10.1
AAVID 30 x 30 x 9.4 mm Pin Fin	2 m/s	8.9
AAVID 35 x 31 x 23 mm Pin Fin	Natural Convection	12.3
AAVID 35 x 31 x 23 mm Pin Fin	0.5 m/s	9.3
AAVID 35 x 31 x 23 mm Pin Fin	1 m/s	8.5
AAVID 35 x 31 x 23 mm Pin Fin	2 m/s	7.9
AAVID 43 x 41 x 16.5 mm Pin Fin	Natural Convection	12.5
AAVID 43 x 41 x 16.5 mm Pin Fin	0.5 m/s	9.7
AAVID 43 x 41 x 16.5 mm Pin Fin	1 m/s	8.5
AAVID 43 x 41 x 16.5 mm Pin Fin	2 m/s	7.7
Wakefield, 53 x 53 x 25 mm Pin Fin	Natural Convection	10.9
Wakefield, 53 x 53 x 25 mm Pin Fin	0.5 m/s	8.5
Wakefield, 53 x 53 x 25 mm Pin Fin	1 m/s	7.5
Wakefield, 53 x 53 x 25 mm Pin Fin	2 m/s	7.1

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink vendors include the following list:

Aavid Thermalloy 603-224-9988
80 Commercial St.
Concord, NH 03301
Internet: www.aavidthermalloy.com

Alpha Novatech 408-749-7601
473 Sapena Ct. #12
Santa Clara, CA 95054
Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277
413 North Moss St.
Burbank, CA 91502
Internet: www.ctscorp.com

This table summarizes the signal impedance targets. The driver impedance are targeted at minimum VDD, nominal NVDD, 105°C.

Table 76. Impedance Characteristics

Impedance	Local Bus, Ethernet, DUART, Control, Configuration, Power Management	PCI Signals (not including PCI Output Clocks)	PCI Output Clocks (including PCI_SYNC_OUT)	DDR DRAM	Symbol	Unit
R_N	42 Target	25 Target	42 Target	20 Target	Z_0	Ω
R_P	42 Target	25 Target	42 Target	20 Target	Z_0	Ω
Differential	NA	NA	NA	NA	Z_{DIFF}	Ω

Note: Nominal supply voltages. See Table 1, T_j = 105°C.

25.6 Configuration Pin Multiplexing

The MPC8314E provides the user with power-on configuration options that can be set through the use of external pull-up or pull-down resistors of 4.7 kΩ on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While $\overline{\text{HRESET}}$ is asserted however, these pins are treated as inputs. The value presented on these pins while $\overline{\text{HRESET}}$ is asserted, is latched when $\overline{\text{PORESET}}$ deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Careful board layout with stubless connections to these pull-up/pull-down resistors coupled with the large value of the pull-up/pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

25.7 Pull-Up Resistor Requirements

The MPC8314E requires high resistance pull-up resistors (10 kΩ is recommended) on open drain type pins including I^2C pins and EPIC interrupt pins.

For more information on required pull up resistors and the connections required for JTAG interface, see AN3438, MPC8315 Design Checklist

26 Ordering Information

Ordering information for the parts fully covered by this specification document is provided in Section 26.1, “Part Numbers Fully Addressed by this Document.”

26.1 Part Numbers Fully Addressed by this Document

This table provides the Freescale part numbering nomenclature for the MPC8314E. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local Freescale sales office. In addition to the processor frequency, the part numbering scheme